

OX-209

Ultra Low Phase Noise Oven Controlled Crystal Oscillator



The OX-209 is an Ultra Low Phase Noise Ovenized Crystal Oscillator with a noise floor as low as -175 dBc/Hz. Designed for applications that demand extremely low noise sources, including the reference oscillator for a phase-locked loop in the microwave spectrum. Custom frequencies available upon request.

Features

- -115 dBc/ Hz at 10 Hz offset
- -175 dBc/Hz at 10 kHz offset
- 20 to 35 MHZ standard, other frequencies available

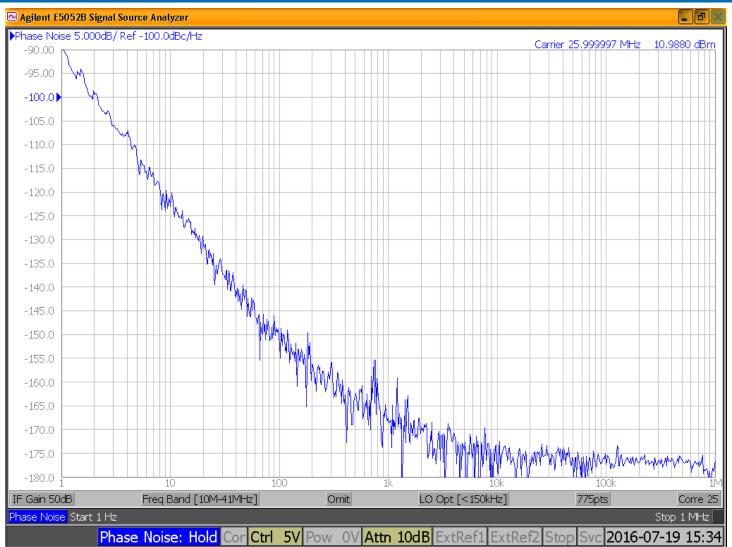
Applications

- Military Radar
- Instrumentation and Test Equipment
- Synthesizers
- Military Communication Equipment
- DRO reference
- Satellite Communications

Performance Specifications

Phase Noise at 20-35 MHz									
Frequency Offset (Hz)	Min	Ту	pical	Max	Unit	Condition			
1				-85					
10				-115		All EFC settings			
100				-145	dBc/Hz				
1000				-160]				
10,000				-170					
100,000				-175					
Frequency Stabilities at 20-35 MHz									
Parameter	Min	Typical	Max	Unit	Condition				
vs. operating temperature range	-30		+30	ppb	-20 to +70°C (refe	erenced to +25°C)			
	-50		+50	ppb	-40 to +85°C (refe	erenced to +25°C)			
vs. Initial Tolerance	-500		+500	ppb	at time of shipment and 5V efc				
Allan Deviation			8	E-12	0.1 to 1 second tau				
vs. supply voltage change	-5		+5	ppb	±5% change				
vs. load change	-5		+5	ppb	5% change in load				
vs. aging / 1 day	-1		+1	ppb	after 30 days of operation				
vs. aging / 1 st year	-100		+100	ppb	after 30 days	of operation			
vs. aging / Year	-50		+50	ppb	after first yea	r of operation			
Warm up time			5	minutes		-hour frequency 25℃			

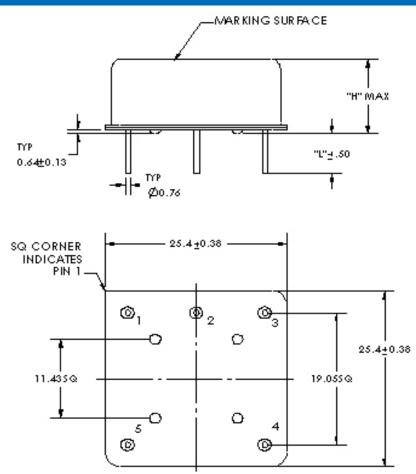
Phase Noise



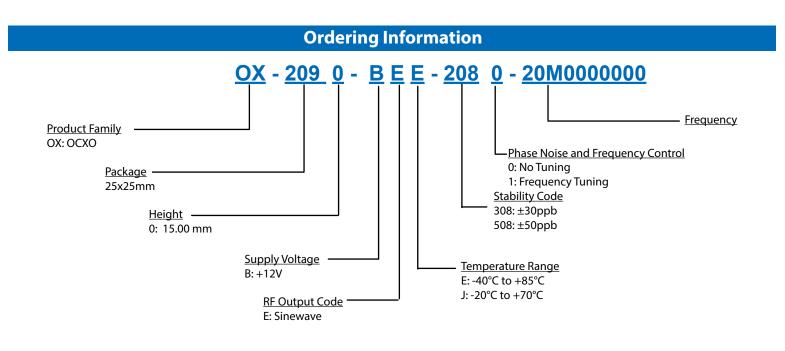
Performance Specifications

Supply Voltage (Vs)								
Parameter	Min	Typical	Max	Unit	Condition			
Supply Voltage	11.4	12.0	12.6	VDC				
Deuron Consumption			4.0	Watts	during warm-up			
Power Consumption			1.8	Watts	steady state @ +25°C			
Reference Voltage		10		VDC				
			RF Output					
Signal	Sinewave							
Load		50		Ohms				
Output Power	+7.0		+13.0	dBm	50 Ohm load			
Harmonics			-30	dBc	50 Ohm load			
Spurious			-80	dBc	50 Ohm load			
		Freque	ncy Tuning	(EFC)				
Tuning Range	±600		±2000	ppb	enough for aging over 10 year lifetime			
Linearity			15	%				
Tuning Slope	Positive							
Control Voltage Range	0		10	VDC				
Input Impedance		100		kOhm				
Modulation Bandwidth	150			Hz				
		Additio	onal Param	eters				
g-sensitivity			1.5	ppb/g				
Weight			20	grams				
	·	Absolute	Maximum	Ratings	-			
Parameter	Min	Typical	Мах	Unit	Condition			
Supply Voltage (Vs)			15	V	12V version			
Output Load			25	Ohms				
Operable Temperature Range	-55		+95	°C	Device will not sustain damage when operated at temperatures between the operating range and the operable range, but will not be specification compliant			
	Envi	ronmental	and Produc	t Classificatio	n			
Shock (Endurance)	MIL-STD-202	MIL-STD-202, Method 213, Condition J, 30g 11 ms						
Sine Vibration (Endurance)	MIL-STD-202, Method 201 and 204, Condition A, except 5g to 500 Hz, 1 sweep each axis							
Random Vibration (Endurance)	MIL-STD-202, Method 214, Condition I-D							
Humidity	MIL-STD-202, Method 103, Condition B, 100% rh							
Seal	MIL-STD-202, Method 112, Condition D							
Altitude	MIL-STD-202, Method 105, sea level to space							
Resistance to Soldering Heat	MIL-STD-202, Method 210, Condition A,B,C							
Terminal Strength	MIL-STD-202, Method 11, Condition C (5 bends at 45°, 2 lbs)							
Moisture Sensitive Level	1							
RoHS	6 (fully compliant) - no pure tin options available upon request, the device will be assigned a customer part number , not orderable through ordering codes							
			_	5				

Outline Drawing



Code	Height "H"	Pin Length "L" Min			
0	15.0	6.2			
Pin Connections					
1	RF Output				
2	Ground (Case)				
3	Electronic Frequency Control Input (EFC)/ No Connect				
4	Reference Voltage				
5	Supply Voltage Input (VS)				



Notes:

- 1. Contact factory for improved stabilities or additional product options including no pure tin options.
- 2. Certain codes available for sampling and short lead time requests. Please review website for codes.
- 3. Unless otherwise stated, all values are valid after warm-up time and refer to typical conditions for supply voltage, frequency control voltage, load, and temperature (25°C).
- 4. Contact factory for other frequencies. Phase noise degrades as frequency increases.
- 5. Subject to technical modification.
- 6. Contact factory for availability.



Microsemi Headquarters One Enterprise, Aliso Viejo, CA 92656 USA Within the USA: +1 (800) 713-4113 Outside the USA: +1 (949) 380-6100 Sales: +1 (949) 380-6136 Fax: +1 (949) 215-4996 email: sales.support@microsemi.com www.microsemi.com Microsemi, a wholly owned subsidiary of Microchip Technology Inc. (Nasdaq: MCHP), offers a comprehensive portfolio of semiconductor and system solutions for aerospace & defense, communications, data center and industrial markets. Products include high-performance and radiation-hardened analog mixed-signal integrated circuits, FPGAs, SoCs and ASICs, power management products; timing and synchronization devices and precise time solutions, setting the world's standard for time; voice processing devices; RF solutions; discrete components; enterprise storage and communication solutions, security technologies and scalable anti-tamper products; Ethernet solutions; Power-over-Ethernet ICs and midspans; as well as custom design capabilities and services. Learn more at www microsemi.com.

Microsemi makes no warranty, representation, or guarantee regarding the information contained herein or the suitability of its products and services for any particular purpose, nor does Microsemi assume any liability whatsoever arising out of the application or use of any product or circuit. The products sold hereunder and any other products sold by Microsemi have been subject to limited testing and should not be used in conjunction with mission-critical equipment or applications. Any performance specifications are believed to be reliable but are not verified, and Buyer must conduct and complete all performance and other testing of the products, solar and to together with, or installed in, any verd-products. Buyer shall not rely on any data and performance specifications or parameters provided by Microsemi. It is the Buyer's responsibility to independently determine suitability of any products and verify the same. The information provided by Microsemi hereunder is provided 'as is, where is' and with all faults, and the entire risk associated with such information is entirely with the Buyer. Microsemi does not grant, explicitly or implicitly to any party any patent rights, licenses, or any other iP mights, whether with regard to such information itself or anything described by such information. Information provided in this document is proprietary to Microsemi to the only conserving and werify to make any changes to the information in this document or to any products and a services at any time without notice.

©2018 Microsemi, a wholly owned subsidiary of Microchip Technology Inc. All rights reserved. Microsemi and the Microsemi logo are registered trademarks of Microsemi Corporation. All other trademarks and service marks are the property of their respective owners.